NSN 5961-01-049-7767

Diode Semiconductor Device - Page 1 of 1



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Overall Length: Between 0.360 inches and 0.375 inches Overall Diameter: Between 0.190 inches and 0.205 inches Features Provided: Hermetically sealed case Semiconductor Material: Silicon Power Rating Per Characteristic: 1500.0 watts small-signal input power, common-collector of standard range
Overall Diameter: Between 0.190 inches and 0.205 inches Features Provided: Hermetically sealed case Semiconductor Material: Silicon Power Rating Per Characteristic:
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Hermetically sealed case Semiconductor Material: Silicon Power Rating Per Characteristic:
Semiconductor Material: Silicon Power Rating Per Characteristic:
Silicon Power Rating Per Characteristic:
Power Rating Per Characteristic:
-
1500.0 watts small-signal input power, common-collector of standard range
Special Features:
Bipolar
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0